





SPECIFICATION FOR 3.3V CMOS SMT TCXO MtronPTI P/N M6300S135

Electrical Specifications:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Frequency of Operation	Fo		40.000000		MHz	
Frequency Tolerance		-1.0		+1.0	ppm	@ +25°C
		F	requency Sta	ability		
vs. Temperature	ΔF/F			4.6	ppm	(Max-Min)/2
vs. Aging		-3		+3	ppm	1 st year
		-1		+1	ppm	Per year thereafter.
			RF Outpu	ıt		
Output Type		C	MOS Compatib	le		
Output Load				15	pF	
Symmetry (duty cycle)	T _{DC}	45		55	%	Ref. to ½ V _{DD}
Logic "1" Level	Vон	80% V _{DD}			V	HCMOS load
Logic "0" Level	V _{OL}			20% V _{DD}	V	HCMOS load
Rise/Fall Time	T _R /T _F			6	ns	From 20% to 80% V _{DD}
	S	Supply Vo	Itage & Powe	r Consum	ption	
Operating Voltage	Vcc	3.135	3.300	3.465	V	
Operating Current	Icc			90	mA	

Environmental Conditions:

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions	
Operating Temperature	TA	-55		+125	°C		
Storage Temperature	Ts	-55		+125	°C		
Shock	Per MIL-S	TD-202, M	ethod 213, Con	dition C (10	0 g's, 6 ms	duration, ½ sinewave)	
Vibration	Per MIL-S	TD-202, M	ethod 201 & 20	4 (10 g's fro	m 10-2000	Hz)	
Thermal Shock	Per MIL-STD-883, Method 1011, Condition A						
Thermal Cycle	Per MIL-S	MIL-STD-883, Method 1010, Condition B					
Hermeticity	Per MIL-STD-202, Method 112 (1 x 10 ⁻⁸ atm cc/s of helium)						
Moisture Sensitivity Level (MSL)	MSL 1						
Solderability	Per EIAJ-STD-002						
Max. Soldering Conditions	See Figure	e 1.					
Package Type 6-pad 5.0 X 7.0 X 1.9 mm leadless ceramic. RoHS compliant.				nt.			

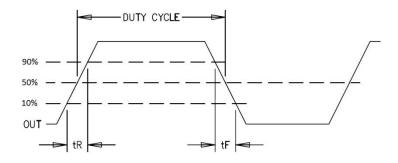




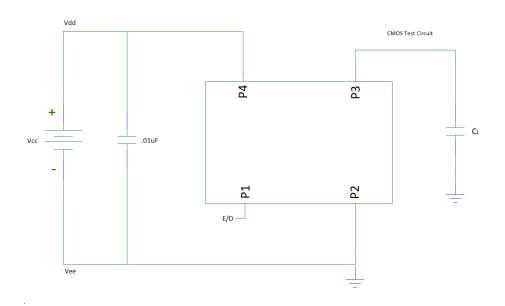


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Output Waveform:



Typical Test Circuit & Load Circuit Diagrams:









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Soldering Conditions:

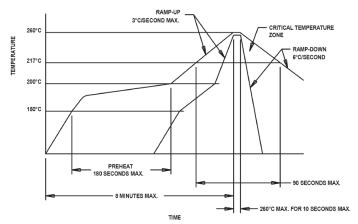
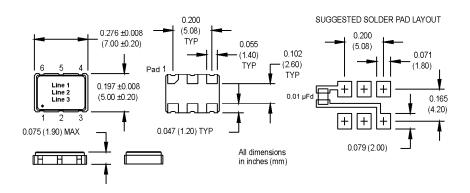


Figure 1

Mechanical, Marking, and Pin Out Information:



Datasheet Revision Table:

Date	Rev.	Author	Details of Revision
01-06-20	Α	BRR	Same as -S099.